

Modeling TLS scrambling due to radiation impacts

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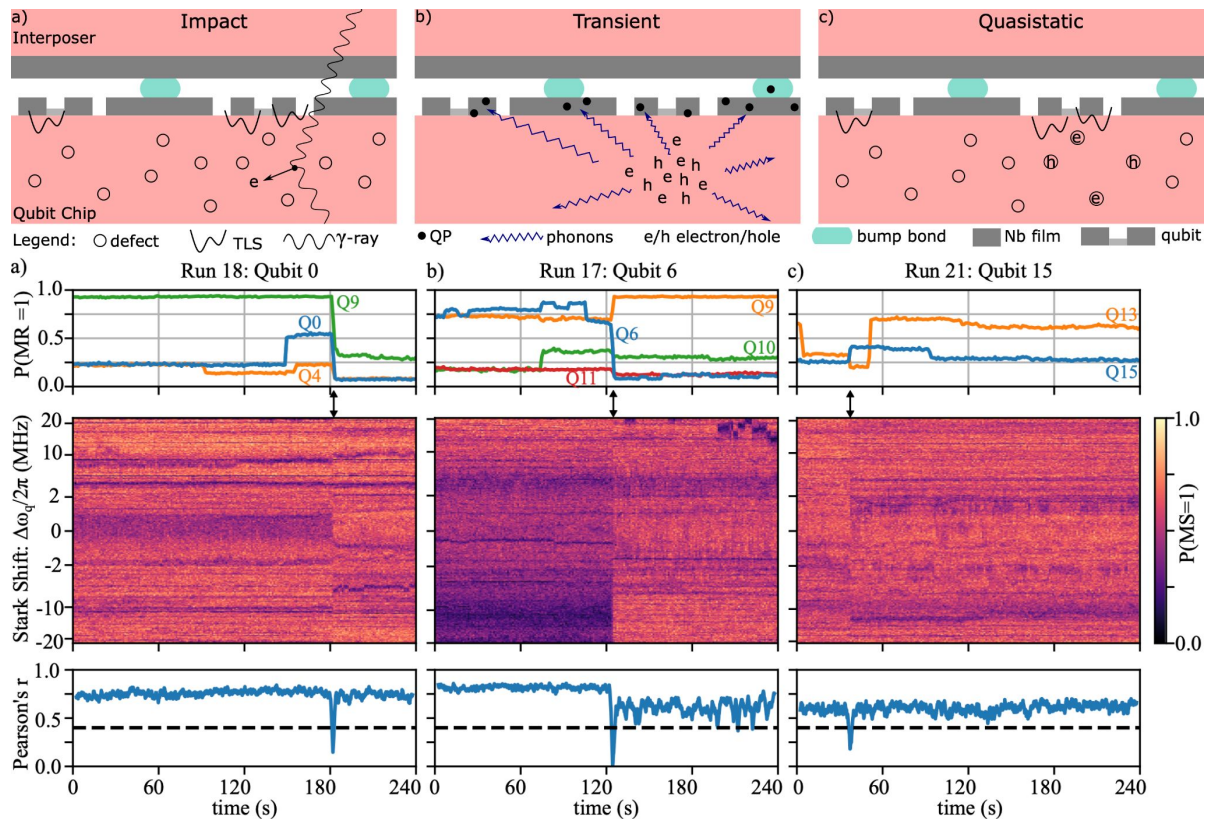
Motivation

EM simulations

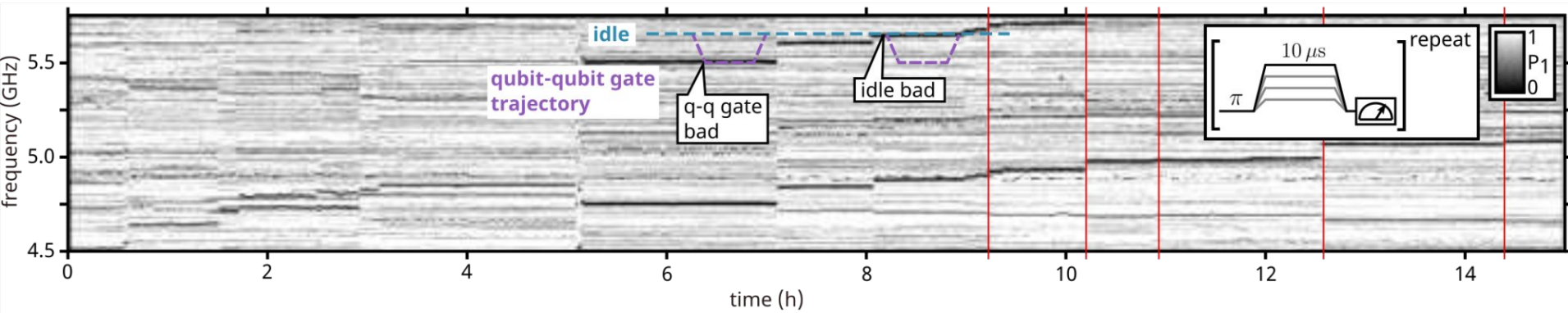
G4 simulations

Results

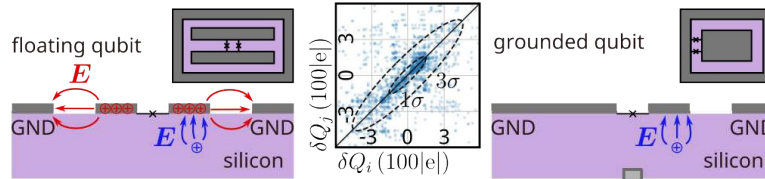
What is TLS scrambling?



Why do we want to mitigate TLS scrambling?



TLS spectroscopy

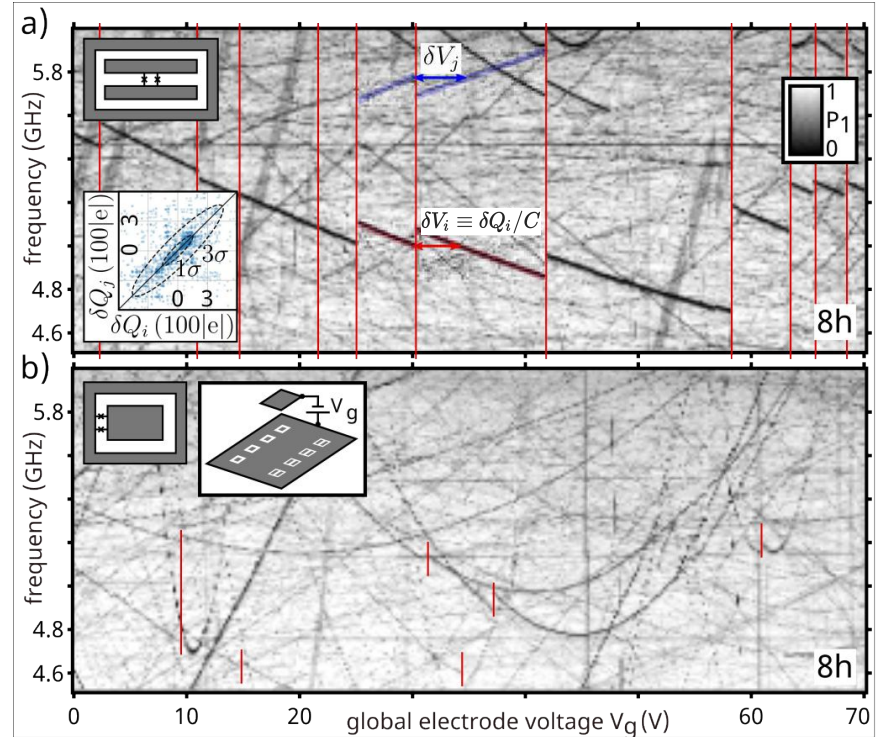


$$\omega_{\text{TLS}} = \sqrt{\Delta_i^2 + (\epsilon_i + 2\mathbf{p}_i \cdot \mathbf{E})^2}$$

TLS frequency can be tuned using a global DC electrode

Scrambling events show correlated jumps

Scrambling events are rare for grounded qubits



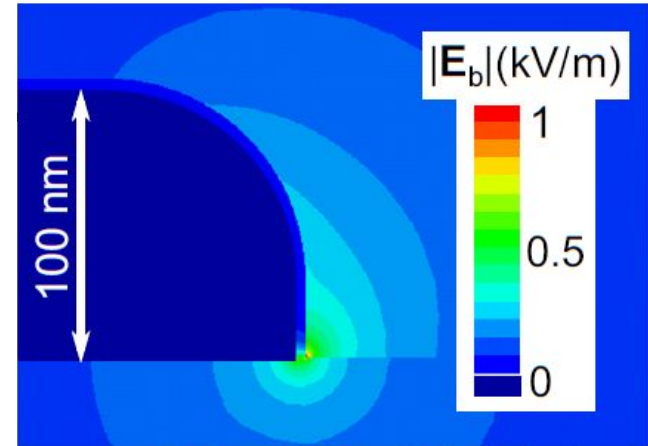
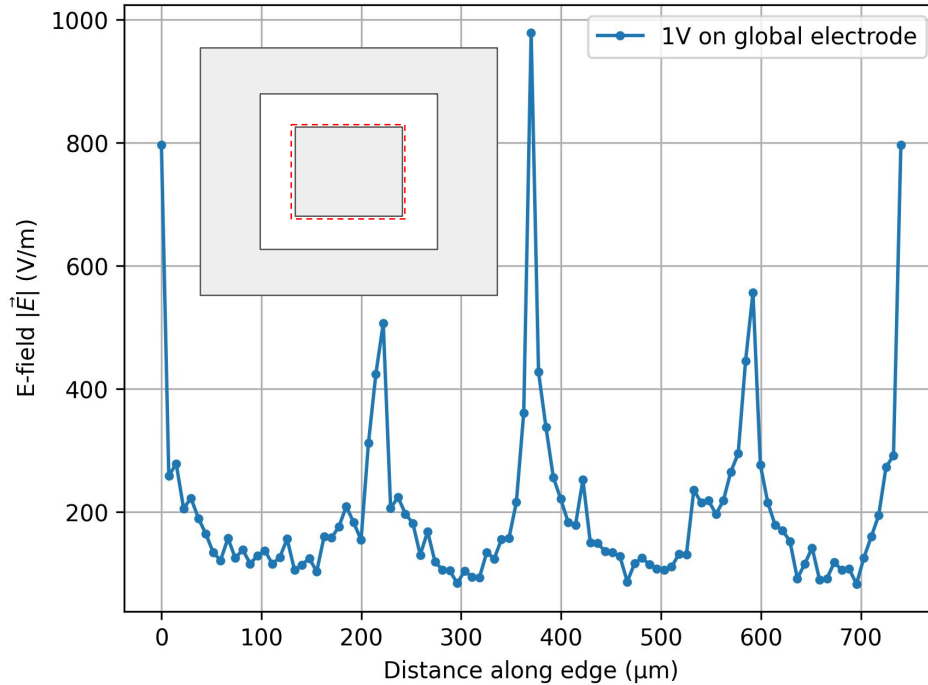
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Ansys simulation of E-field from global electrode

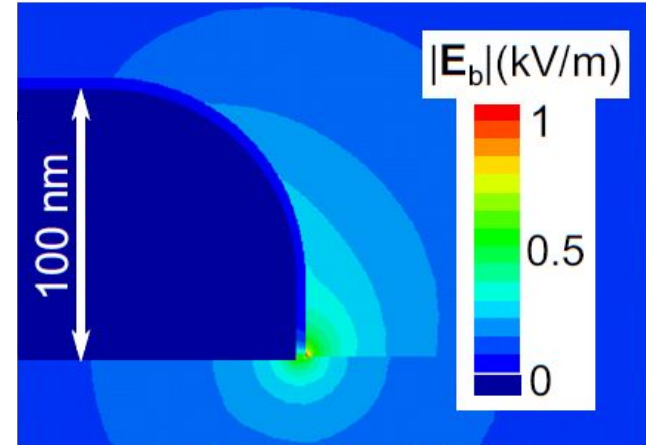
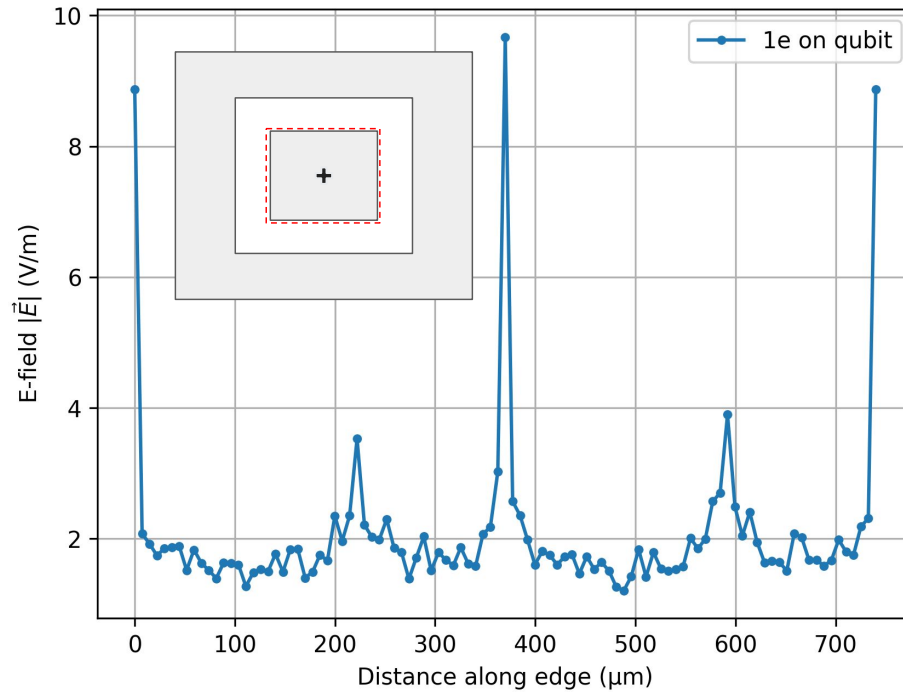


Bilmes et al. Scientific Reports **10**, 3090 (2020)

The strongest fields are at the edge of the qubit near the qubit-substrate interface

We will focus on surface TLS at this edge

Anslys simulation of E-field from charged qubit

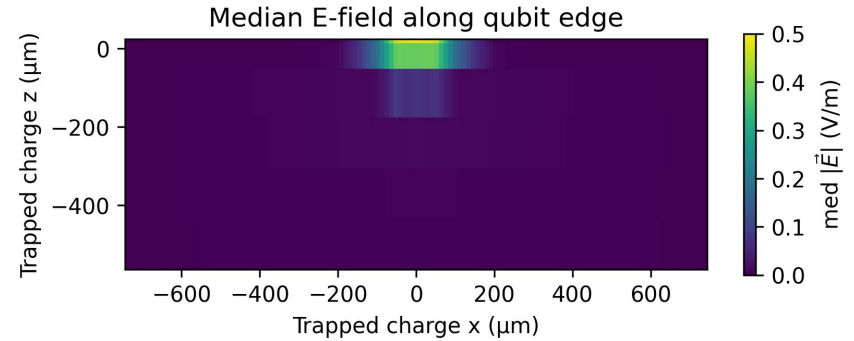
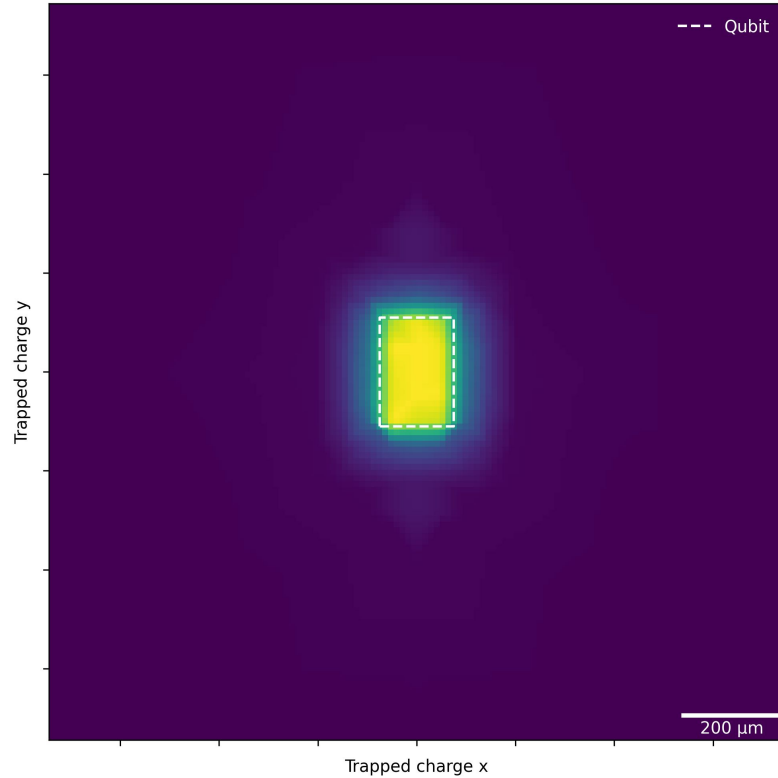


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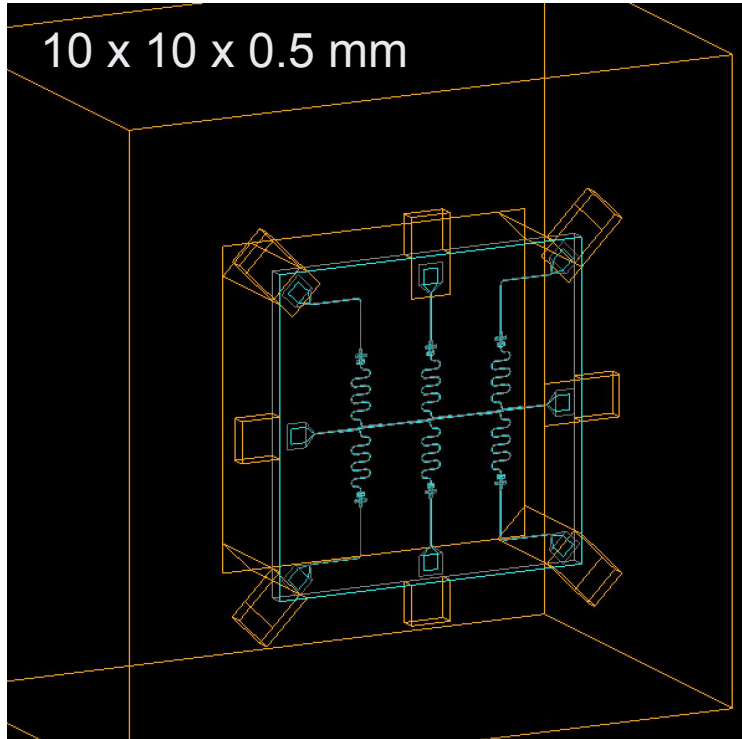
Ansys simulation of E-field from trapped substrate charge



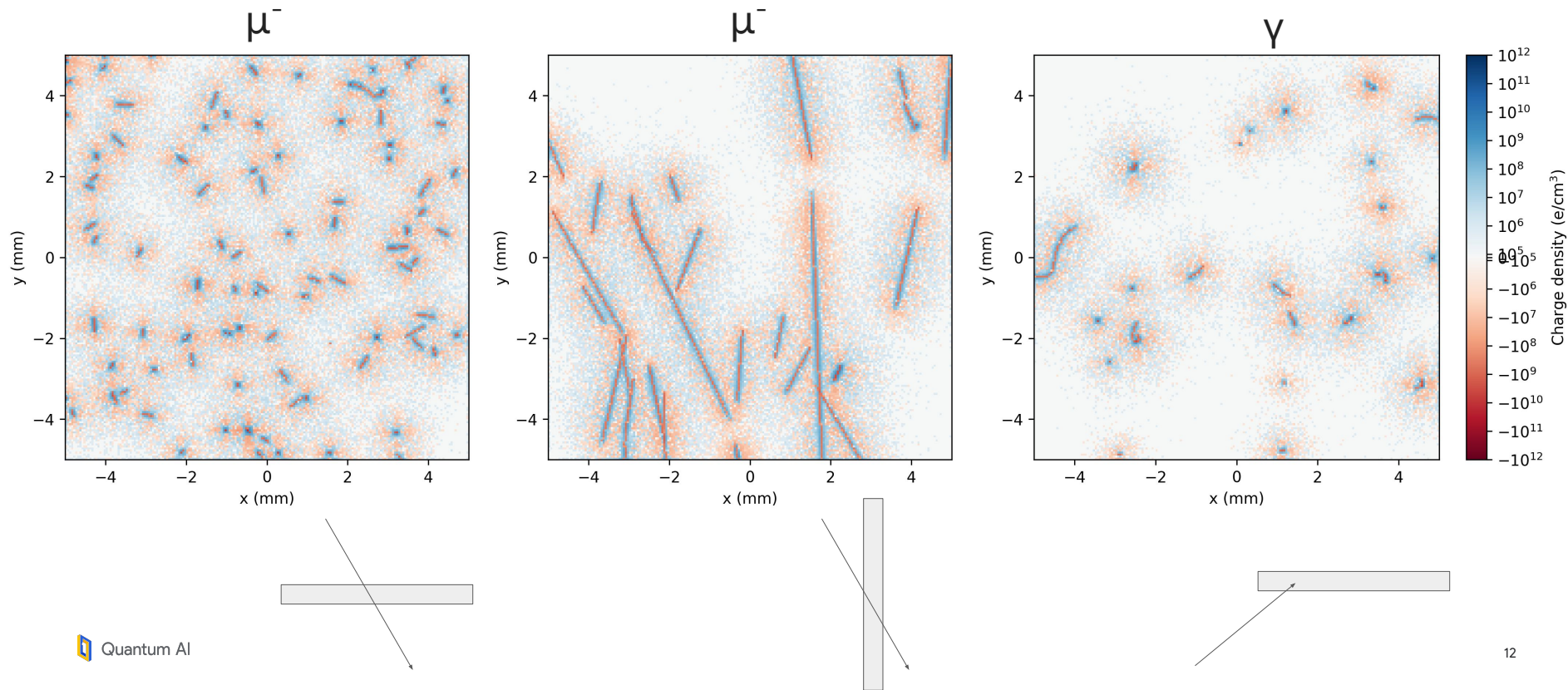
Fields from trapped charges in the substrate are local

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G4 simulations
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Geometry

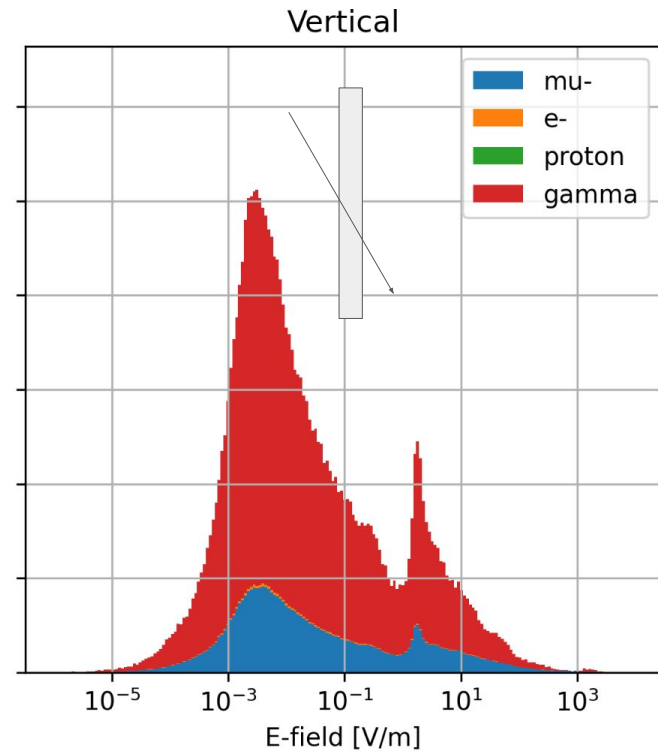
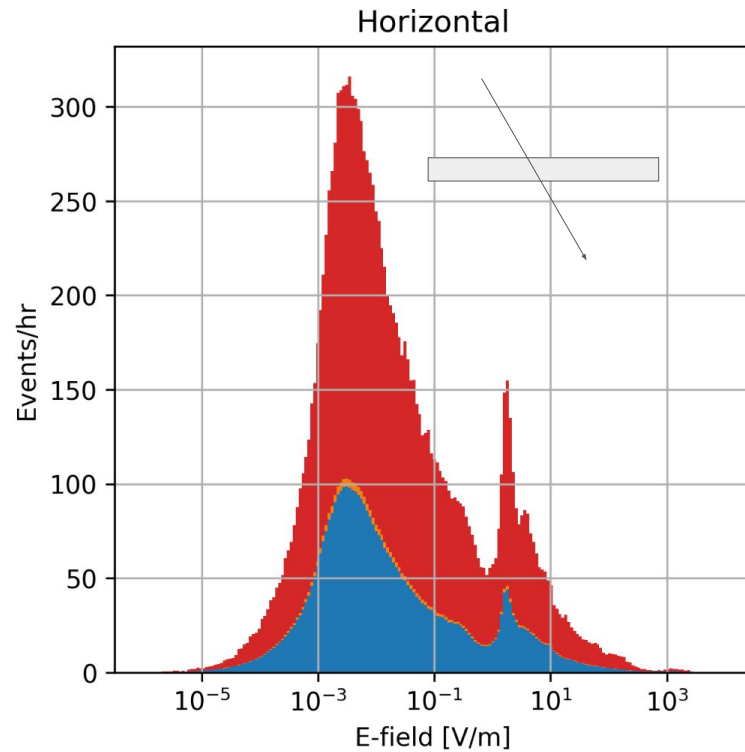


Charge density of trapped electrons and holes

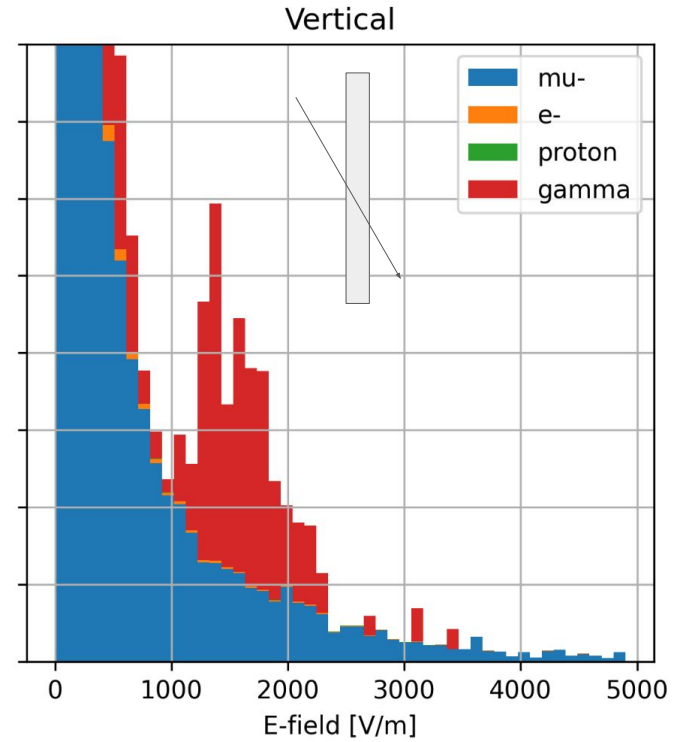
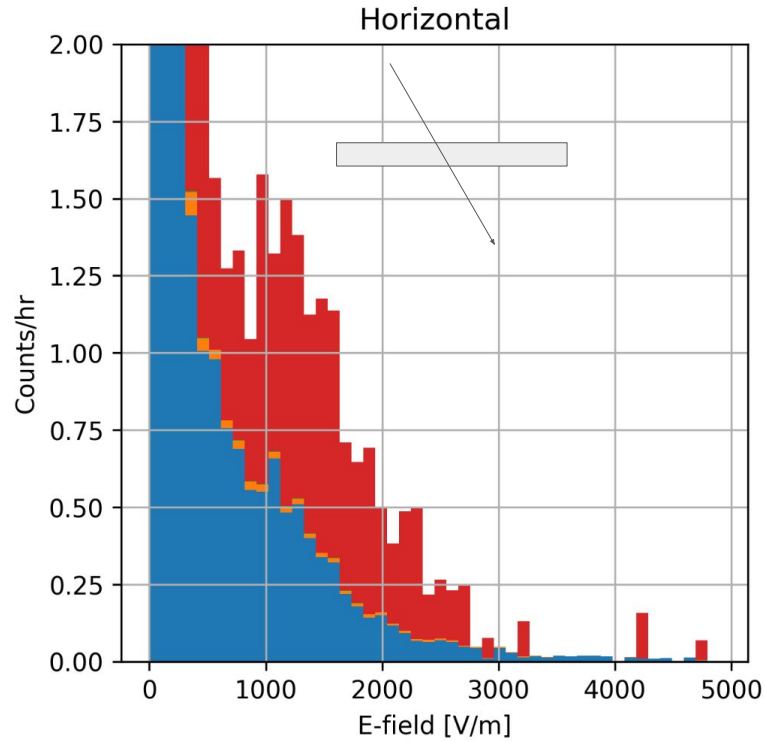


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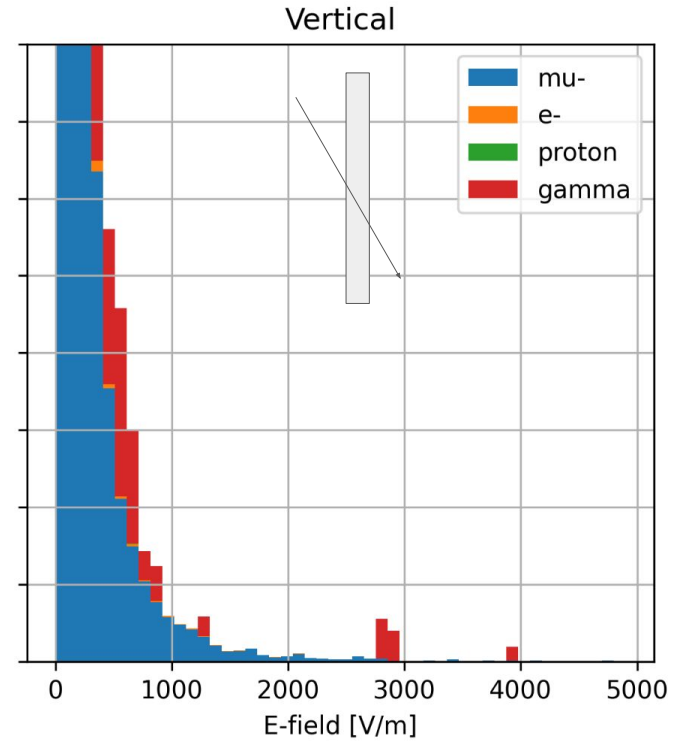
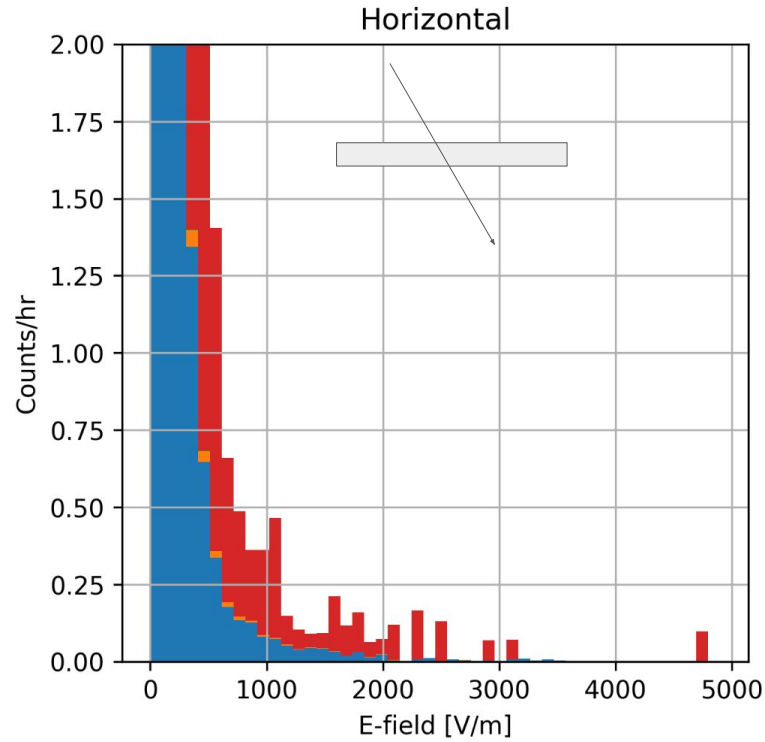
E-field jump distribution for floating qubit



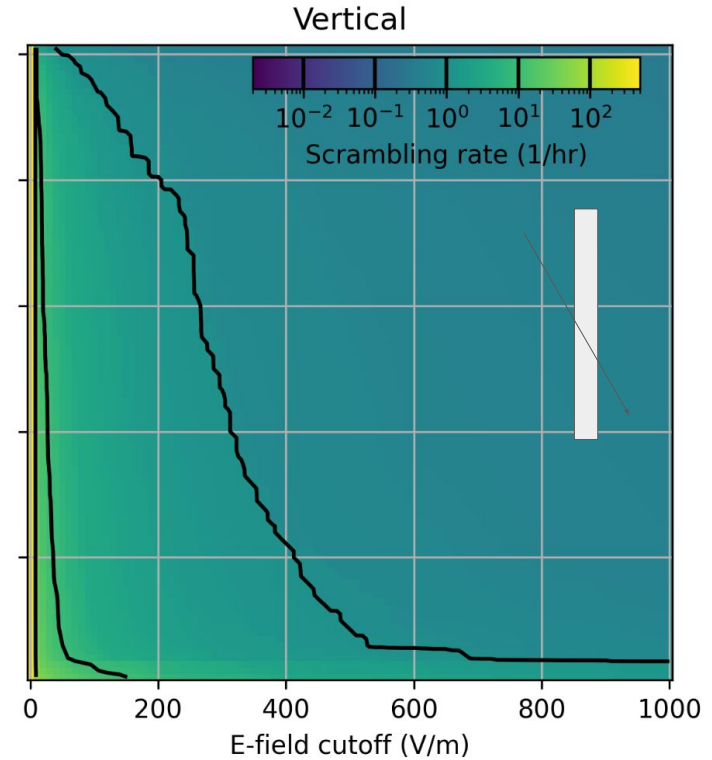
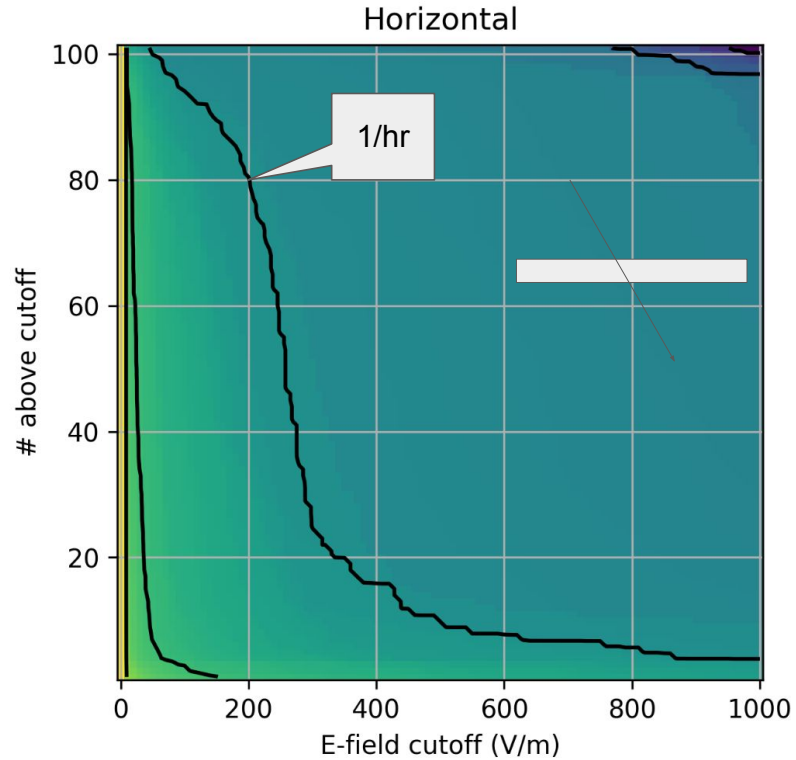
E-field jump distribution for floating qubit



E-field jump distribution for grounded qubit



Scrambling rate



Thank you!



Quantum AI